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# First/Second Semester B.E. Degree Examination, June/July 2019 **Basic Electronics**

Max. Marks: 100 Time: 3 hrs.

Note: Answer any FIVE full questions, choosing ONE full question from each module.

Module-1

- What is PN junction diode? With the help of circuit diagram, explain the VI characteristics 1 (07 Marks) of a diode.
  - What is rectifier circuit? Explain the classification of the rectifier. Derive the following (08 Marks) expressions for Half-wave rectifier: (i)  $I_{dc}$  (ii)  $I_{rms}$  (iii)  $\eta$  (iv)  $\gamma$
  - c. Design a Zener diode voltage regulator circuit to meet the following specifications:  $I_L = 20 \text{ mA}$ ,  $V_0 = 5V$ ,  $P_z = 500 \text{ mW}$ ,  $V_i = 12 \pm 2V$  and  $I_{zmin} = 8 \text{ mA}$ . (05 Marks)

- What is a transistor? What are its applications? Explain the various current gains in a 2 (07 Marks) transistor and derive the relation between  $\alpha$  and  $\beta$ .
  - b. With a neat circuit diagram, explain the input and output characteristics of the common (08 Marks) emitter configuration.
  - c. Explain the operation of full wave rectifier with capacitor filter. (05 Marks)

Module-2

- For the base bias circuit,  $V_{CC}=18V$ ,  $R_{C}=2.2$  K $\Omega$ ,  $R_{B}=470$  K $\Omega$  and  $\beta=100$ . Find  $I_{B}$ ,  $I_{C}$ 3 and V<sub>CE</sub>. Draw the DC load line and locate the operating point. (07 Marks)
  - Draw the circuit diagram of the voltage divider biasing circuit. Derive the expressions of IB (05 Marks) and V<sub>CE</sub>.
  - List out the various deal op-amp characteristics. Explain the terms CMRR and Slew rate. (08 Marks)

OR

- Derive the output equation of the inverting adder. Design an adder op-amp circuit to obtain an output voltage  $V_0 = -(0.1V_1 + 0.5V_2 + 20V_3)$ . Select  $R_f = 10 \text{ K}\Omega$ . (07 Marks)
  - b. What is an integrator? Derive its output equation.

(05 Marks)

- Derive the output expressions for the following op-amp applications:
  - (i) Voltage follower
- (ii) Subtractor

(08 Marks)

Module-3

- What are Radix-2, Radix-8, Radix-10 and Radix-16 number system? Perform the following 5 operations:
  - i)  $(1234.56)_8 = (?)_{10}$
- ii)  $(BAD.DAD)_{16} = (?)_8$
- iii)  $(988.86)_{10} = (?)_{16}$

(08 Marks)

- b. Perform the following using 2's complement method:
  - i)  $(15)_{10} (28)_{10}$
- ii)  $(1011.10)_2 (1000.01)_2$

(05 Marks)

- Write the symbol and truth table of the following gates:
  - i) AND
- ii) NOR
- iii) XOR
- iv) NAND

(07 Marks)

#### OR

- 6 a. Simplify and realize the following Boolean expressions using basic gates:
  - i)  $Y = \overline{A} \overline{B} \overline{C} + \overline{A} \overline{B} \overline{C} + \overline{A} \overline{B} + A\overline{B}$
  - ii)  $Y = ABC + A\overline{B}C + AB\overline{C} + \overline{A}BC$
  - iii)  $Y = (\overline{A} + \overline{B})(\overline{A} + \overline{C})(\overline{B} + C)$

(08 Marks)

b. Implement XOR gate using only NOR gates.

(05 Marks)

c. Write truth table of half-adder and full-adders. Realize the full-adder using two half-adders.

(07 Marks)

### Module-4

- 7 a. What is flip-flop and latch? Explain the operation of SR latch using NAND gates. (07 Marks)
  - b. Explain the working of clocked SR flip-flop with a suitable logic diagram and a truth table.

(08 Marks)

c. Explain the working of NAND gate latch and NOR gate latch.

(05 Marks)

## OR

- 8 a. What is microcontroller? List out the main features of 8051 microcontroller. (05 Marks)
  - b. With a neat block diagram, explain the architecture of 8051 microcontroller. (09 Marks)
  - c. What is stepper motor? Explain the working and interfacing of stepper motor to a 8051 microcontroller. (06 Marks)

### Module-5

- 9 a. What is amplitude modulation and frequency modulation? With the help of neat waveform, derive the expression for AM wave. (07 Marks)
  - b. A carrier signal with  $A_C = 40$  V and  $f_c = 1$  MHz is amplitude modulated with a modulating signal  $A_m = 4$  V and  $f_m = 2.5$  kHz. The depth of the modulation is 75%. Calculate the following: (i)  $P_C$  (ii)  $P_T$  (iii)  $P_{SB}$  (iv) BW (v) Sideband frequencies. Assume  $R = 2\Omega$ .
    - c. What is demodulation? Explain the working of AM detector circuit.

#### OR

- 10 a. What is transducer? Explain the working of resistance transducer and resistance thermometer. (07 Marks)
  - b. What is LVDT? Explain the construction, operation and applications of LVDT. (07 Marks)
  - c. Explain the working of piezoelectric and photoelectric transducers.

(06 Marks)

(06 Marks)

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